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# FSQ0370RNA, FSQ0370RLA

## Green Mode Fairchild Power Switch (FPS™)

### Features

- Internal Avalanche Rugged 700V SenseFET
- Consumes Only 0.8W at 230V<sub>AC</sub> & 0.5W Load with Burst-Mode Operation
- Precision Fixed Operating Frequency: 100kHz
- Internal Startup Circuit and Built-in Soft-Start
- Pulse-by-Pulse Current Limiting, Auto-Restart Mode
- Over-Voltage Protection (OVP), Overload Protection (OLP), Internal Thermal Shutdown Function (TSD)
- Under-Voltage Lockout (UVLO)
- Low Operating Current: 3mA
- Adjustable Peak Current Limit

### Applications

- Auxiliary Power Supply for PC and Server
- SMPS for VCR, SVR, STB, DVD, and DVCD Player
- Printer, Facsimile, and Scanner
- Adapter for Camcorder

### Description

The FSQ0370 consists of an integrated Current Mode Pulse Width Modulator (PWM) and an avalanche rugged 700V SenseFET. It is specifically designed for high-performance offline Switched Mode Power Supplies (SMPS) with minimal external components. The integrated PWM controller features include: a fixed-frequency generating oscillator, Under-Voltage Lockout (UVLO) protection, Leading-Edge Blanking (LEB), an optimized gate turn-on / turn-off driver, Thermal Shutdown (TSD) protection, and temperature-compensated precision current sources for loop compensation and fault protection circuitry.

Compared to a discrete MOSFET and controller or RCC switching converter solution, the FSQ0370 reduces total component count, design size, and weight while increasing efficiency, productivity, and system reliability. These devices provide a basic platform that is well suited for the design of cost-effective flyback converters, such as in PC auxiliary power supplies.

### Related Application Notes

- [AN-4134 — Design Guidelines for Off-line Forward Converters Using Fairchild Power Switch \(FPS™\)](#)
- [AN-4137 — Design Guidelines for Offline Flyback Converters Using Fairchild Power Switch \(FPS™\)](#)
- [AN-4141 — Troubleshooting and Design Tips for Fairchild Power Switch \(FPS™\) Flyback Applications](#)
- [AN-4147 — Design Guidelines for RCD Snubber of Flyback Converters](#)

### Ordering Information

Part Number	Package	Marking Code	BV <sub>DSS</sub>	f <sub>osc</sub>	R <sub>DS(ON)(MAX)</sub>
FSQ0370RNA	8-Lead, Dual Inline Package (DIP)	Q0370RA	700V	100KHz	4.75Ω
FSQ0370RLA	8-Lead, LSOP				

## Application Circuit

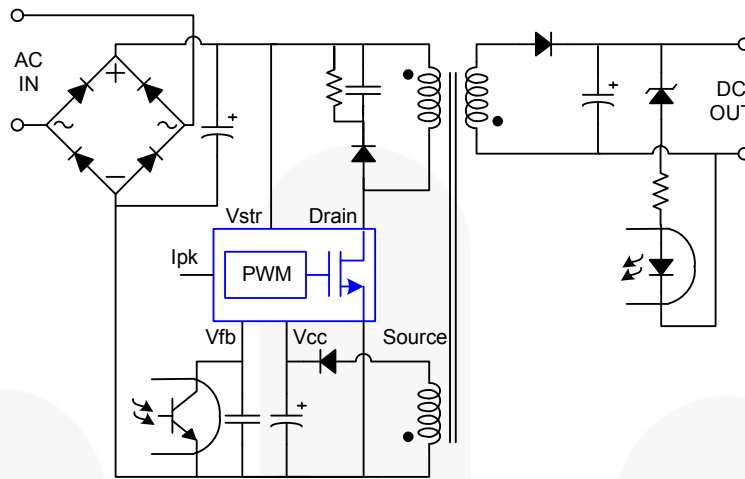


Figure 1. Typical Flyback Application

Table 1. Output Power Table<sup>(1)</sup>

Product	230V <sub>AC</sub> ±15% <sup>(2)</sup>		85-265V <sub>AC</sub>	
	Adapter <sup>(3)</sup>	Open Frame <sup>(4)</sup>	Adapter <sup>(3)</sup>	Open Frame <sup>(4)</sup>
F5CQ0370RNA	20W	27W	13W	19W
F5CQ0370RLA				

### Notes:

1. The maximum output power can be limited by junction temperature.
2. 230V<sub>AC</sub> or 100/115V<sub>AC</sub> with doubler.
3. Typical continuous power in a non-ventilated enclosed adapter with sufficient drain pattern as a heat sink at 50°C ambient.
4. Maximum practical continuous power in an open-frame design with sufficient drain pattern as a heat sink at 50°C ambient.

## Internal Block Diagram

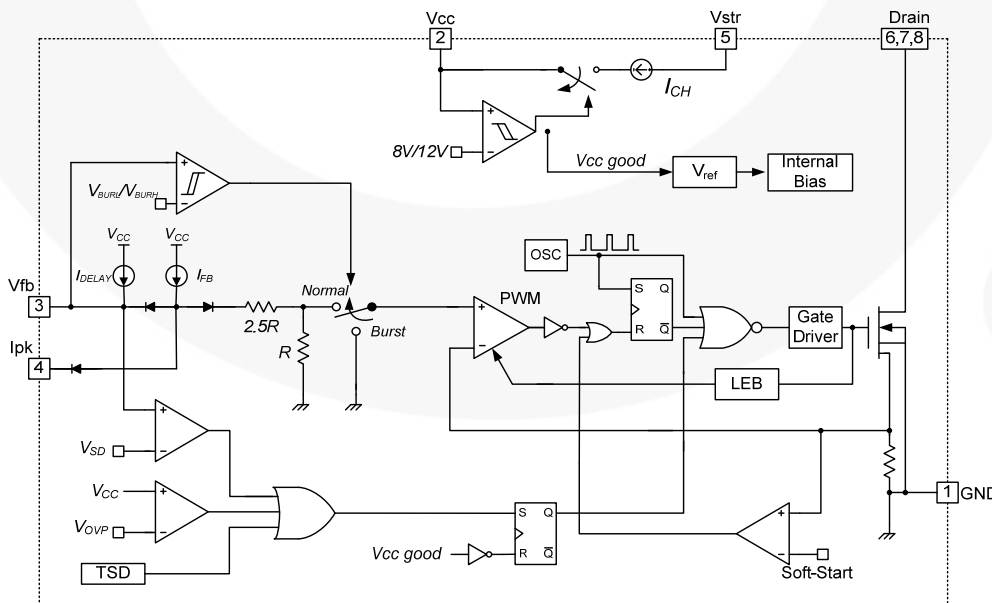
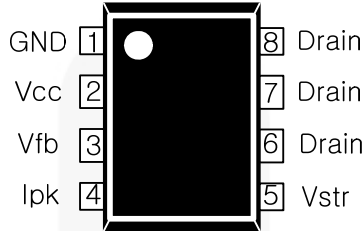


Figure 2. Functional Block Diagram

## Pin Assignments



**Figure 3. Pin Configuration (Top View)**

## Pin Definitions

Pin#	Name	Description
1	GND	SenseFET source terminal on the primary side and internal control ground.
2	V <sub>cc</sub>	Positive supply voltage input. Although connected to an auxiliary transformer winding, current is supplied from pin 5 (V <sub>str</sub> ) via an internal switch during startup (see Figure 2). It is not until V <sub>CC</sub> reaches the UVLO upper threshold (12V) that the internal startup switch opens and device power is supplied via the auxiliary transformer winding.
3	V <sub>fb</sub>	The feedback voltage pin is the non-inverting input to the PWM comparator. It has a 0.9mA current source connected internally, while a capacitor and optocoupler are typically connected externally. A feedback voltage of 6V triggers overload protection (OLP). There is a delay while charging external capacitor C <sub>fb</sub> from 3V to 6V using an internal 5μA current source. This delay prevents false triggering under transient conditions, but allows the protection mechanism to operate in true overload conditions.
4	I <sub>pk</sub>	This pin adjusts the peak current limit of the SenseFET. The 0.9mA feedback current source is diverted to the parallel combination of an internal 2.8kΩ resistor and any external resistor to GND on this pin. This determines the peak current limit. If this pin is tied to V <sub>cc</sub> or left floating, the typical peak current limit is 1.1A.
5	V <sub>str</sub>	This pin is connected to the rectified AC line voltage source. At startup, the internal switch supplies internal bias and charges an external storage capacitor placed between the V <sub>cc</sub> pin and ground. Once V <sub>CC</sub> reaches 12V, the internal switch is opened.
6, 7, 8	Drain	The drain pins are designed to connect directly to the primary lead of the transformer and are capable of switching a maximum of 700V. Minimizing the length of the trace connecting these pins to the transformer decreases leakage inductance.

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A=25^{\circ}\text{C}$ , unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
$V_{\text{DRAIN}}$	Drain Pin Voltage	700		V
$V_{\text{STR}}$	Vstr Pin Voltage	700		V
$I_{\text{DM}}$	Drain Current Pulsed <sup>(5)</sup>		12	A
$E_{\text{AS}}$	Single Pulsed Avalanche Energy <sup>(6)</sup>		230	mJ
$V_{\text{CC}}$	Supply Voltage		20	V
$V_{\text{FB}}$	Feedback Voltage Range	-0.3	$V_{\text{CC}}$	V
$P_{\text{D}}$	Total Power Dissipation		1.5	W
$T_{\text{J}}$	Recommended Operating Junction Temperature	-40	Internally Limited	$^{\circ}\text{C}$
$T_{\text{A}}$	Operating Ambient Temperature	-40	+85	$^{\circ}\text{C}$
$T_{\text{STG}}$	Storage Temperature	-55	+150	$^{\circ}\text{C}$

### Notes:

5. Non-repetitive rating; pulse-width limited by maximum junction temperature.
6.  $L=51\text{mH}$ , starting  $T_{\text{J}}=25^{\circ}\text{C}$ .

## Thermal Impedance

Symbol	Parameter	Value	Unit
$\theta_{\text{JA}}$	Junction-to-Ambient Thermal Resistance <sup>(7)</sup>	80	$^{\circ}\text{C}/\text{W}$
$\theta_{\text{JC}}$	Junction-to-Case Thermal Resistance <sup>(8)</sup>	20	
$\Psi_{\text{JT}}$	Junction-to-Top Thermal Resistance <sup>(9)</sup>	35	

### Notes:

7. Free-standing with no heat-sink, without copper clad.
8. Measured on the drain pin, close to the plastic interface.
9. Measured on the package top surface.

## Electrical Characteristics

T<sub>A</sub>=25°C unless otherwise specified.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>SenseFET Section<sup>(10)</sup></b>						
I <sub>DSS</sub>	Zero-Gate-Voltage Drain Current	V <sub>DS</sub> =700V, V <sub>GS</sub> =0V			50	μA
		V <sub>DS</sub> =560V, V <sub>GS</sub> =0V, T <sub>C</sub> =125°C			200	
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance <sup>(10)</sup>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A		4.00	4.75	Ω
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		315		pF
C <sub>OSS</sub>	Output Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		47		pF
C <sub>RSS</sub>	Reverse Transfer Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		9		pF
t <sub>d(on)</sub>	Turn-On Delay	V <sub>DD</sub> =350V, I <sub>D</sub> =1A		11.2		ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> =350V, I <sub>D</sub> =1A		34		ns
t <sub>d(off)</sub>	Turn-Off Delay	V <sub>DD</sub> =350V, I <sub>D</sub> =1A		28.2		ns
t <sub>f</sub>	Fall Time	V <sub>DD</sub> =350V, I <sub>D</sub> =1A		32		ns
<b>Control Section</b>						
f <sub>OSC</sub>	Switching Frequency		92	100	108	kHz
Δf <sub>OSC</sub>	Switching Frequency Variation <sup>(11)</sup>	-25°C < T <sub>J</sub> < 85°C		±5	±10	%
D <sub>MAX</sub>	Maximum Duty Cycle	Measured at 0.1 x V <sub>DS</sub>	55	60	650	%
D <sub>MIN</sub>	Minimum Duty Cycle		0	0	0	%
V <sub>START</sub>	UVLO Threshold Voltage	V <sub>FB</sub> =GND	11	12	13	V
V <sub>STOP</sub>			7	8	9	
I <sub>FB</sub>	Feedback Source Current	V <sub>FB</sub> =GND	0.7	0.9	1.1	mA
t <sub>S/S</sub>	Internal Soft-Start Time <sup>(11)</sup>	V <sub>FB</sub> =4V		10		ms
<b>Burst-Mode Section</b>						
V <sub>BURH</sub>	Burst-Mode Voltage	T <sub>J</sub> =25°C	0.5	0.6	07	V
V <sub>BURL</sub>			0.3	0.4	0.5	V
V <sub>BUR(HYS)</sub>			100	200	300	mV
<b>Protection Section</b>						
I <sub>LIM</sub>	Peak Current Limit	di/dt=240mA/μs	0.97	1.10	1.23	A
t <sub>CLD</sub>	Current Limit Delay <sup>(11)</sup>			500		ns
T <sub>SD</sub>	Thermal Shutdown Temperature <sup>(11)</sup>		125	140		°C
V <sub>SD</sub>	Shutdown Feedback Voltage		5.5	6.0	6.5	V
V <sub>OVP</sub>	Over-Voltage Protection		18	19		V
I <sub>DELAY</sub>	Shutdown Delay Current	V <sub>FB</sub> =4V	3.5	5.0	6.5	μA
t <sub>LEB</sub>	Leading-Edge Blanking Time <sup>(11)</sup>		200			ns
<b>Total Device Section</b>						
I <sub>OP</sub>	Operating Supply Current (Control Part Only)	V <sub>CC</sub> =14V	1	3	5	mA
I <sub>CH</sub>	Startup Charging Current	V <sub>CC</sub> =0V	0.70	0.85	1.00	mA
V <sub>STR</sub>	V <sub>STR</sub> Supply Voltage	V <sub>CC</sub> =0V		24		V

### Notes:

10. Pulse test: Pulse width ≤ 300μs, duty ≤ 2%.

11. These parameters, although guaranteed, are not 100% tested in production.

## Typical Performance Characteristics

Characteristic graphs are normalized at  $T_A=25^\circ\text{C}$ .

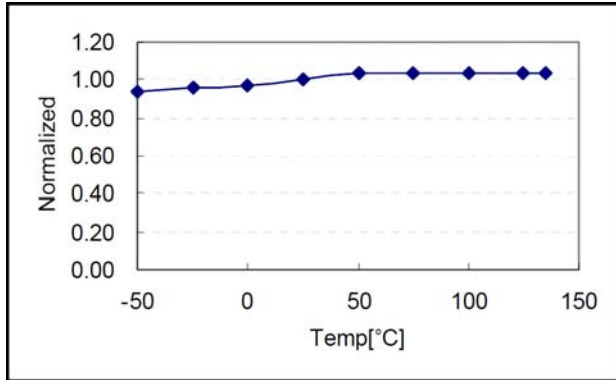


Figure 4. Operating Frequency ( $f_{osc}$ ) vs.  $T_A$

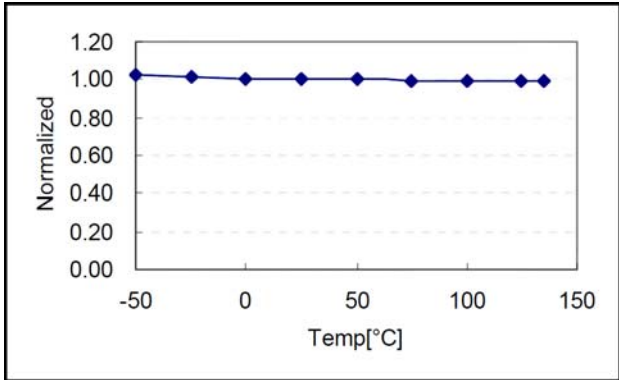


Figure 5. Over-Voltage Protection ( $V_{OVP}$ ) vs.  $T_A$

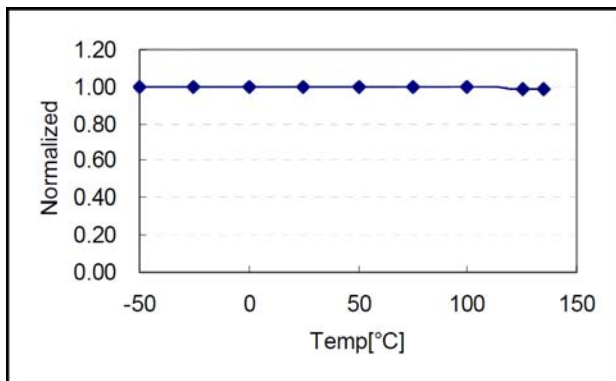


Figure 6. Maximum Duty Cycle ( $D_{MAX}$ ) vs.  $T_A$

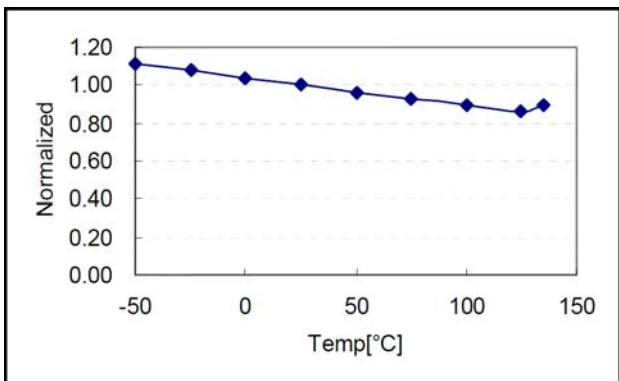


Figure 7. Operating Supply Current ( $I_{OP}$ ) vs.  $T_A$

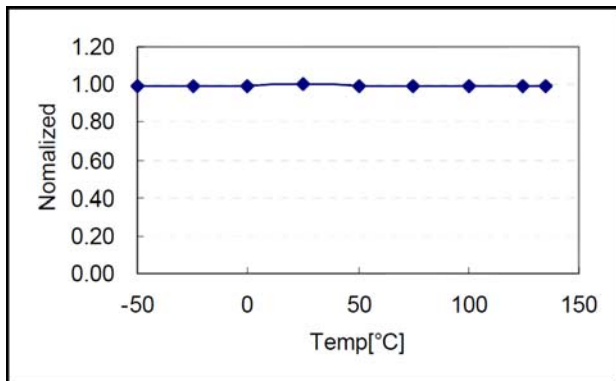


Figure 8. Start Threshold Voltage ( $V_{START}$ ) vs.  $T_A$

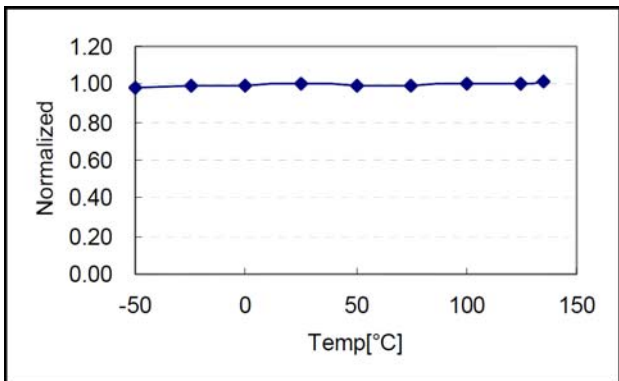


Figure 9. Stop Threshold Voltage ( $V_{STOP}$ ) vs.  $T_A$

## Typical Performance Characteristics

Characteristic graphs are normalized at  $T_A=25^\circ\text{C}$ .

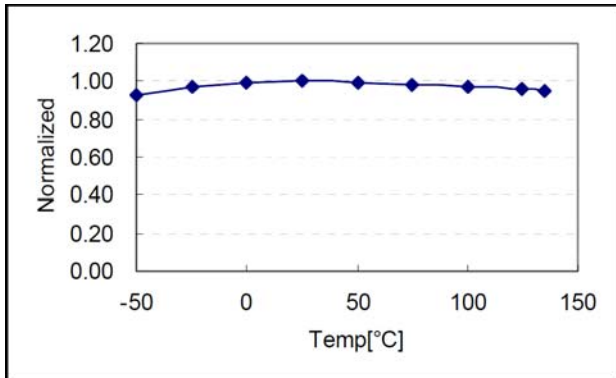


Figure 10. Feedback Source Current ( $I_{FB}$ ) vs.  $T_A$

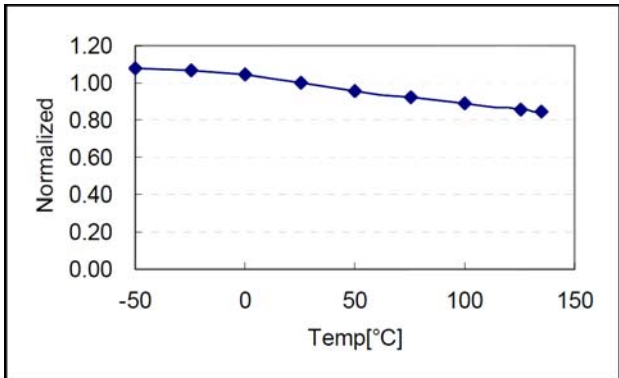


Figure 11. Startup Charging Current ( $I_{CH}$ ) vs.  $T_A$

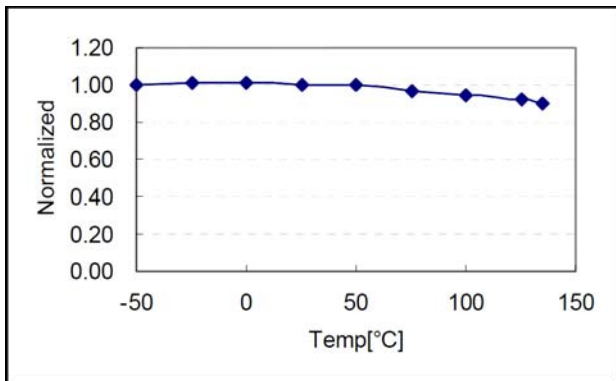


Figure 12. Peak Current Limit ( $I_{LIM}$ ) vs.  $T_A$



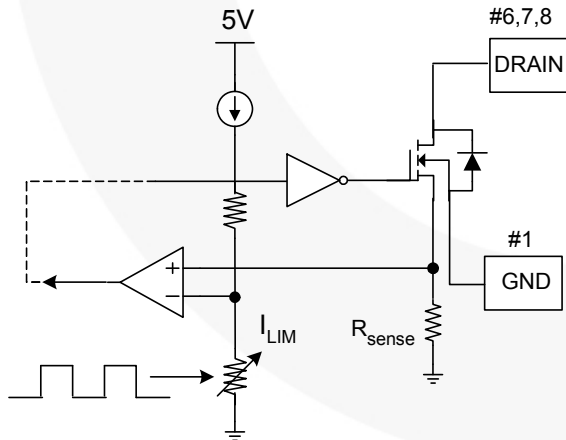




**4.2 Thermal Shutdown (TSD):** The SenseFET and the control IC are integrated, making it easier for the control IC to detect the temperature of the SenseFET. If the temperature exceeds approximately 140°C, thermal shutdown is activated.

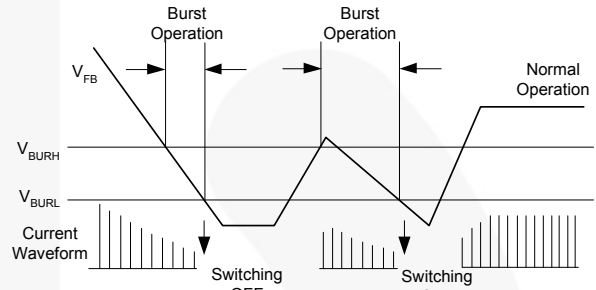
**4.3 Over-Voltage Protection (OVP):** In the event of a malfunction in the secondary-side feedback circuit or an open feedback loop caused by a soldering defect, the current through the optocoupler transistor becomes almost zero (refer to Figure 14). Then,  $V_{FB}$  climbs up in a similar manner to the overload situation, forcing the preset maximum current to be supplied to the SMPS until the overload protection is activated. Because excess energy is provided to the output, the output voltage may exceed the rated voltage before the overload protection is activated, resulting in the breakdown of the devices in the secondary side. To prevent this situation, an Over-Voltage Protection (OVP) circuit is employed. In general,  $V_{CC}$  is proportional to the output voltage and the FPS uses  $V_{CC}$  instead of directly monitoring the output voltage. If  $V_{CC}$  exceeds 19V, the OVP circuit is activated, terminating switching. To avoid undesired activation of OVP during normal operation,  $V_{CC}$  should be designed to be below 19V.

**5. Soft-Start:** The FPS internal soft-start circuit slowly increases the SenseFET current after startup, as shown in Figure 16. The typical soft-start time is 10ms, where progressive increments of the SenseFET current are allowed during the startup phase. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased to smoothly establish the required output voltage. This helps to prevent transformer saturation and reduces the stress on the secondary diode during startup.



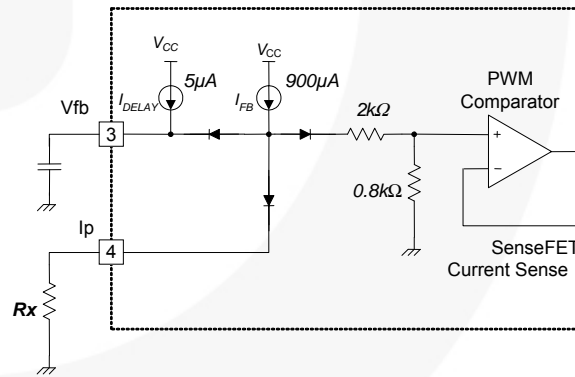
**Figure 16. Soft-Start Function**

**6. Burst Operation:** To minimize power dissipation in Standby Mode, the FPS enters Burst Mode. Feedback voltage decreases as the load decreases and, as shown in Figure 17, the device automatically enters Burst Mode when the feedback voltage drops below  $V_{BURH}$  (typically 600mV). Switching continues until the feedback voltage drops below  $V_{BURL}$  (typically 400mV). At this point, switching stops and the output voltage starts to drop at a rate dependent on the standby current load. This causes the feedback voltage to rise. Once it passes  $V_{BURH}$ , switching resumes. The feedback voltage then falls and the process is repeated. Burst Mode alternately enables and disables switching of the SenseFET and reduces switching loss in Standby Mode.



**Figure 17. Burst Operation Function**

**7. Adjusting Peak Current Limit:** As shown in Figure 18, a combined 2.8kΩ internal resistance is connected to the non-inverting lead on the PWM comparator. An external resistance of  $R_x$  on the current limit pin forms a parallel resistance with the 2.8kΩ when the internal diodes are biased by the main current source of 900μA.



**Figure 18. Peak Current Limit Adjustment**

For example, FSQ0370 has a typical SenseFET peak current limit ( $I_{LIM}$ ) of 1.1A.  $I_{LIM}$  can be adjusted to 0.6A by inserting  $R_x$  between the  $I_{pk}$  pin and the ground. The value of the  $R_x$  can be estimated by:

$$1.1A : 0.6A = 2.8k\Omega : Xk\Omega, \quad (1)$$

$$X = R_x \parallel 2.8k\Omega. \quad (2)$$

where X represents the resistance of the parallel network.



## Typical Application Circuit

Application	Output Power	Input Voltage	Output Voltage (Maximum Current)
PC Auxiliary Power Supply (Using FSQ0270RNA)	15W	Universal Input (85-264V <sub>AC</sub> )	5V (3A)

### Features

- High efficiency (>78% at 115V<sub>AC</sub> and 230V<sub>AC</sub> input)
- Low Standby Mode power consumption (<0.8W at 230V<sub>AC</sub> input and 0.5W load)
- Enhanced system reliability through various protection functions
- Low EMI through frequency modulation
- Internal soft-start: 10ms
- Line UVLO function can be achieved using external components

### Key Design Notes

- The delay for overload protection is designed to be about 30ms with C8 of 47nF. If faster/slower triggering of OLP is required, C8 can be changed to a smaller or larger value (eg. 100nF for 60ms).
- ZP1, DL1, RL1, RL2, RL3, RL4, RL5, RL7, QL1, QL2, and CL9 build a line Under-Voltage Lockout block (UVLO). The Zener voltage of ZP1 determines the input voltage that turns the FPS on. RL5 and DL1 provide a reference voltage from V<sub>CC</sub>. If the input voltage divided by RL1, RL2, and RL4 is lower than the Zener voltage of DL1; QL1, and QL2 turn on and pull V<sub>fb</sub> down to ground.
- An evaluation board and corresponding test report can be provided. Contact a Fairchild representative.



## Transformer

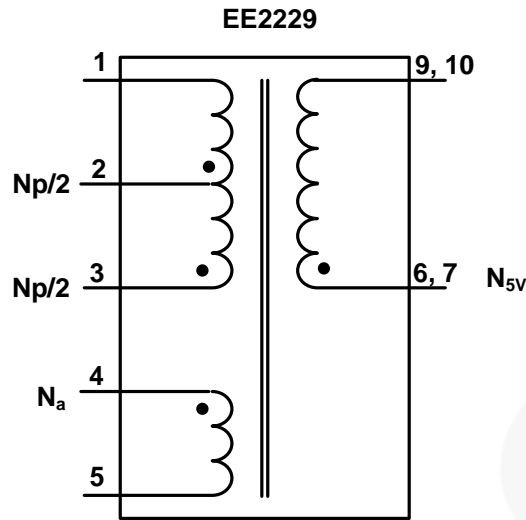


Figure 22. Transformer Schematic Diagram

Table 2. Winding Specification

No.	Pin (s→f)	Wire	Turns	Winding Method
$N_p/2$	3 → 2	0.3 <sup>φ</sup> x 1	72	Solenoid Winding
Insulation: Polyester Tape t = 0.025mm, 1-Layer				
$N_a$	4 → 5	0.25 <sup>φ</sup> x 2	22	Solenoid Winding
Insulation: Polyester Tape t = 0.025mm, 2-Layer				
$N_{5V}$	6, 7 → 9, 10	0.65 <sup>φ</sup> x 2	8	Solenoid Winding
Insulation: Polyester Tape t = 0.025mm, 2-Layer				
$N_p/2$	2 → 1	0.3 <sup>φ</sup> x 1	72	Solenoid Winding
Insulation: Polyester Tape t = 0.025mm, 2-Layer				

Table 3. Electrical Characteristics

	Pin	Specification	Remarks
Inductance	1 - 3	1.20mH ± 5%	100kHz, 1V
Leakage	1 - 3	<30μH Maximum	Short All Other Pins

### Core & Bobbin

- Core: EER2229 ( PL-7, 37.2mm<sup>2</sup>)
- Bobbin: BE2229

**Table 4. Demonstration Board Part List**

Part Number	Value	Quantity	Description (Manufacturer)
C6, C8	47nF	2	Ceramic Capacitor
C1	2.2nF (1KV)	1	AC Ceramic Capacitor(X1 & Y1)
C10	1nF (200V)	1	Mylar Capacitor
CS1	1.5nF (50V)	1	SMD Ceramic Capacitor
C2, C3	22μF (400V)	2	Low Impedance Electrolytic Capacitor KMX series (Samyoung Electronics)
C4, C9	1000μF (16V)	2	Low ESR Electrolytic Capacitor NXC series (Samyoung Electronics)
C5	470μF (10V)	1	Low ESR Electrolytic Capacitor NXC series (Samyoung Electronics)
C7	47μF (25V)	1	General Electrolytic Capacitor
CL9	10μF (50V)	1	General Electrolytic Capacitor
L1	330μH	1	Inductor
L2	1μH	1	Inductor
R6	2.4 (1W)	1	Fusible Resistor
J1, J2, J4, L3	0	4	Jumper
R2	4.7kΩ	1	Resistor
R3	560Ω	1	Resistor
R4	100Ω	1	Resistor
R5	1.25kΩ	1	Resistor
R11	1.2kΩ	1	Resistor
R9	10kΩ	1	Resistor
R10	2Ω	1	Resistor
R14	30Ω	1	Resistor
RL3	1kΩ	1	Resistor
RL1, RL2	1MΩ	2	Resistor
RL4	120kΩ	1	Resistor
RL5	30kΩ	1	Resistor
RL7	40kΩ	1	Resistor
RS1	9Ω	1	Resistor
ZR1	80Ω	1	SMD Resistor
U1	FOD817A	1	IC (Fairchild Semiconductor)
U2	TL431	1	IC (Fairchild Semiconductor)
U3	FSQ0270RNA	1	IC (Fairchild Semiconductor)
QL1	2N2907	1	IC (Fairchild Semiconductor)
QL2	2N2222	1	IC (Fairchild Semiconductor)
D2, D3, D4, D5, D6, DS1	1N4007	6	Diode (Fairchild Semiconductor)
D1	SB540	1	Schottky Diode (Fairchild Semiconductor)
ZD1	1N4745	1	Zener Diode (Fairchild Semiconductor)
DL1	1N5233	1	Zener Diode (Fairchild Semiconductor)
ZP1	82V (1W)	1	Zener Diode (Fairchild Semiconductor)
ZDS1	P6KE180A	1	TVS (Fairchild Semiconductor)

Layout

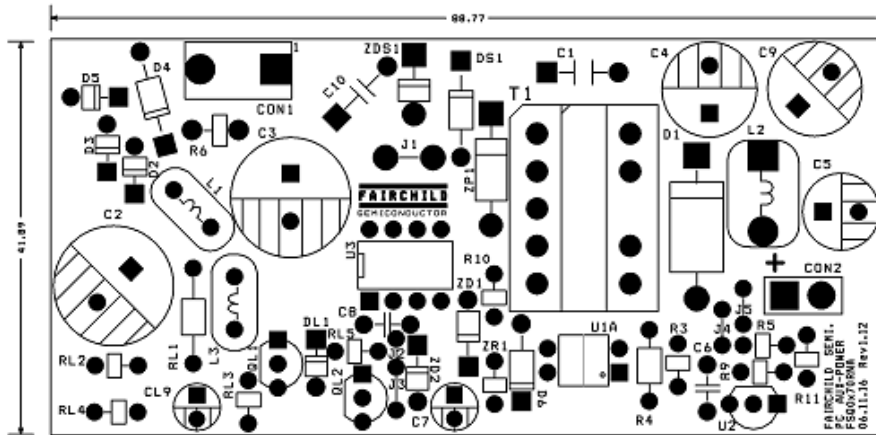


Figure 23. Top Image of PCB

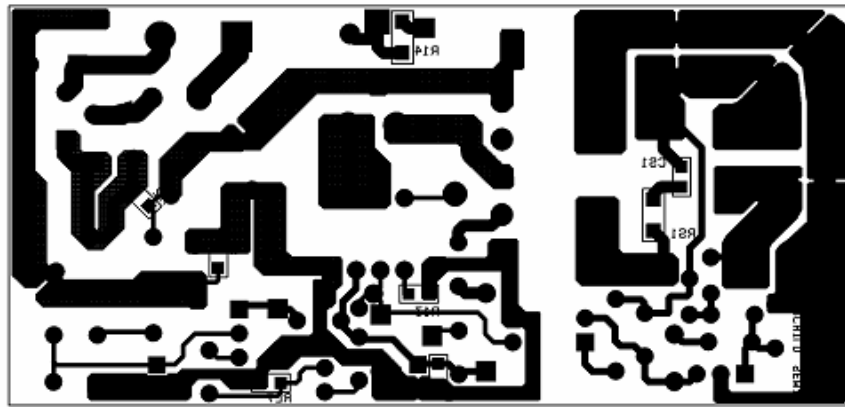
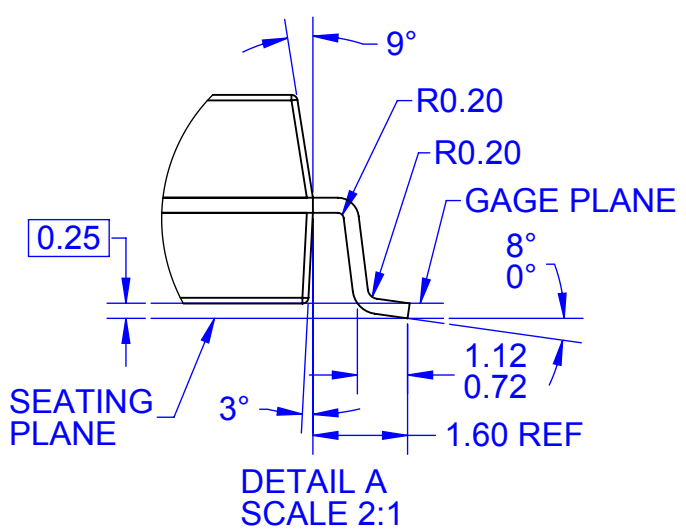
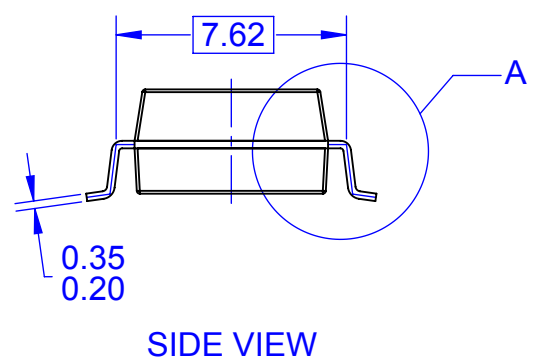
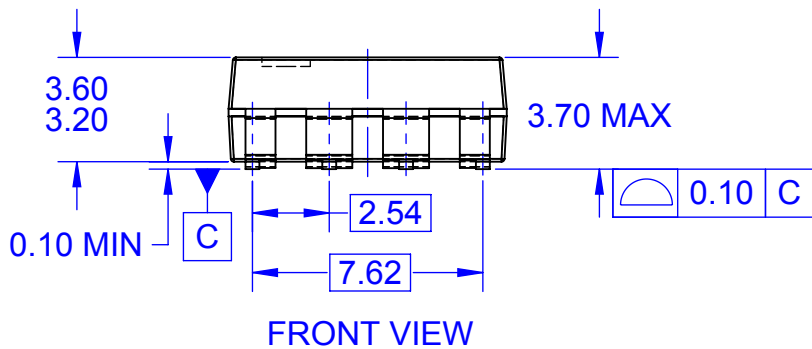
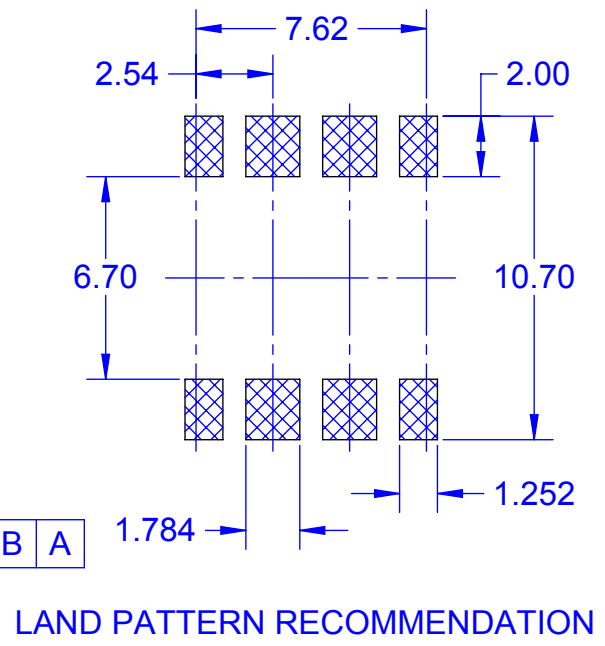
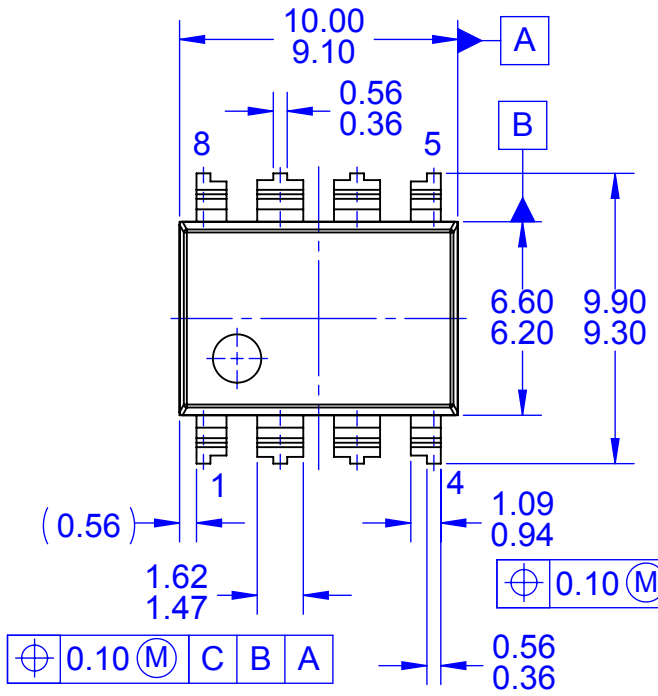


Figure 24. Bottom of Image of PCB

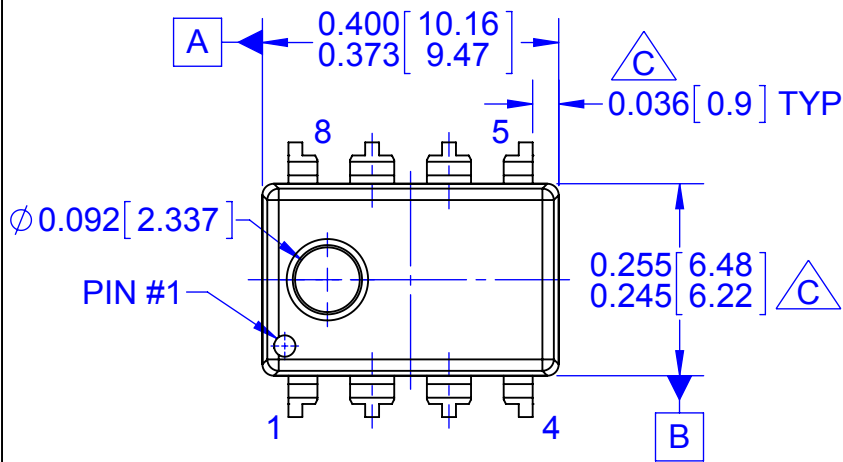




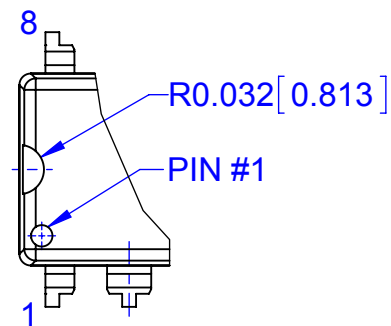


NOTES: UNLESS OTHERWISE SPECIFIED  
 A. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE  
 B. ALL DIMENSIONS ARE IN MILLIMETERS  
 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS  
 D. DIMENSIONS AND TOLERANCES PER ASME Y14.5M-2009  
 E. DRAWING FILENAME: MKT-MLSOP08Arev2

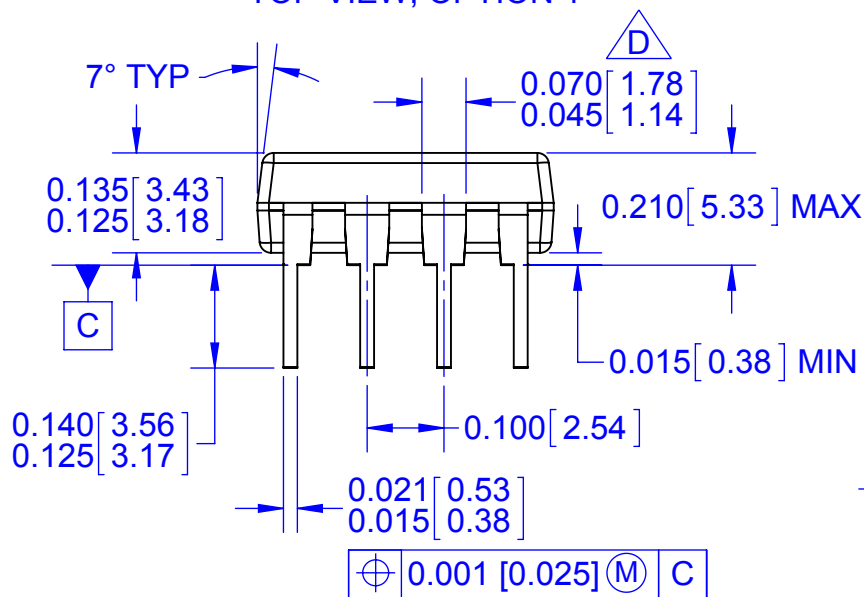




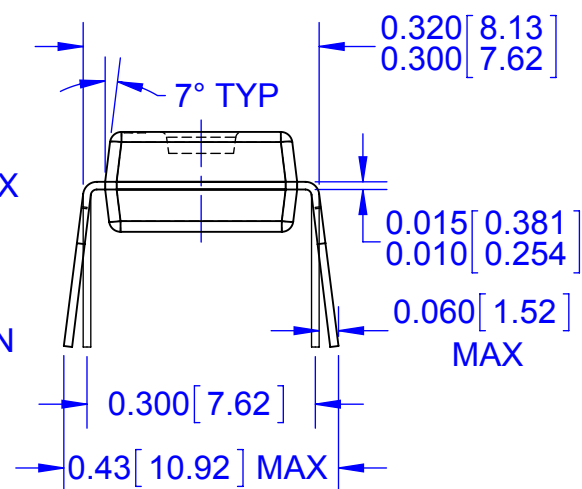
TOP VIEW, OPTION 1



TOP VIEW, OPTION 2



FRONT VIEW



SIDE VIEW

NOTES:

- A. CONFORMS TO JEDEC MS-001, VARIATION BA
- B. CONTROLLING DIMENSIONS ARE IN INCHES.  
REFERENCE DIMENSIONS ARE IN MILLIMETERS.

**C** DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS.  
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED  
0.010 INCHES OR 0.25MM.

**D** DOES NOT INCLUDE DAMBAR PROTRUSIONS.  
DAMBAR PROTRUSIONS SHALL NOT EXCEED 0.010  
INCHES OR 0.25MM.

E. DIMENSIONING AND TOLERANCING PER ASME  
Y14.5M-2009

F. DRAWING FILENAME: MKT-N08Erev8



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